

UMX5601

ULTRA LOW MAGNETIC MOMENT PIN <u>DIODE FOR MRI APPLICATIONS</u>

ROHS COMPLIANT





DESCRIPTION

The UMX5601TM PIN diode series was designed to provide ultra low magnetic PIN diodes for in bore surface coil applications associated with higher field strength (3T and greater) MR scanners. These PIN diodes produce the minimum artifacts (magnetic field distortions) available in the industry, today. The diodes have been tested in magnetic fields of ±7 Tesla.

The UMX5601 PIN diodes have a magnetic moment at 7 T of 4E-8 (J/T).

The diodes are offered in a surface mount package. The SM package utilizes a round end cap to mark the anode. The cathode is square. The fully passivated PIN diode chip is full face metallurgically bonded to shortened high conductive pins for lower thermal and electrical resistances. The PIN diodes feature low forward bias resistance and high zero bias impedance. The UMX5601 PIN diodes are characterized at 64, 128, and 300 MHz. The UMX5601SM meets RoHS requirements per EU Directive 2002/95/EC.

IMPORTANT: For the most current data, consult our website: www.MICROSEMI.com

ABSOLUTE MAXIMUM RATINGS AT 25° C (UNLESS OTHERWISE SPECIFIED)							
Rating	Symbol Value		Unit				
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V _{RRM} V _{RWM} V _R	100 100 100	V				
RMS Reverse Voltage	V _{R (RMS)}	75	V				
Storage Temperature	T stg	-65 to +175	°C				
Operating Temperature Non-Repetitive Peak	Тор	-65 to +150	°C				

KEY FEATURES

- Ultra low magnetic construction
- SOGO passivated chip
- Thermally matched configuration
- RoHS compliant ¹
- Low capacitance at 0 V bias
- Low conductance at 0 V bias
- Metallurgical bond
- Fused-in-glass construction
- Non cavity design
- Available in surface mount package.
- Compatible with automatic insertion equipment
- 1- These devices are supplied with Silver terminations. Other terminal finishes may be available on request. Consult factory for details.

THERMAL CHARACTERISTICS (UNLESS OTHERWISE SPECIFIED)

Thermal Resistance	Symbol	Value	Unit
UMX5601SM	θ	2	°C/Watt



APPLICATIONS/BENEFITS

- High B Field (3T+) in bore APPLICATIONS:
- Active or semi-active (not passive)
- MR blocking circuits
- MR detuning circuits
- MR disable circuits
- MR receiver protector circuits



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Rohs Compliant





ELECTRICAL PARAMETERS @ 25°C (unless otherwise specified)								
Parameter	Symbol	Conditions	Min	Тур.	Max	Units		
Forward Voltage	V _F	I _F = 100 mA		0.75	1.0	V		
Reverse Break Down Voltage	V_{BR}	I _R = 10 uA	100			V		
Reverse Current	I _R	V _R = 100 V			10	uA		
Inductance	Ls			900		рН		
Magnetic moment	m	@ 7T @ 1T		4E-8 1E-7		J/T J/T		
Mass Susceptibility	χρ	@ 7T @ 1T		-3.3E-11 6.5E-10		m³/kg m³/kg		
Volume Susceptibility	χ	>1T to 7T <1T		-3.1E-7 5.9E-6		SI SI		
Capacitance		V _R = 0 V, F = 1 MHz		9	10	pF		
	Ст	V _R = 50 V, F = 1 MHz		2.6	3.0			
Parallel Resistance	В	V _R = 0 V, F = 64 MHz	5	9		kΩ		
	R_P	V _R = 30 V, F = 64 MHz	100	250				
Series Resistance	Rs	If = 100 mA F = 64 MHz		0.3	0.5	Ω		
Lifetime	τ	If = 10 mA	5	10		us		



MAGNETIC MOMENT VS FIELD

UMX5601

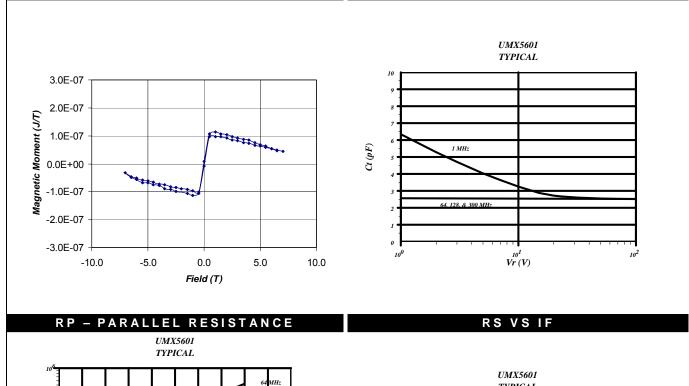
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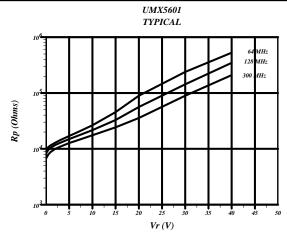
C-V CURVES

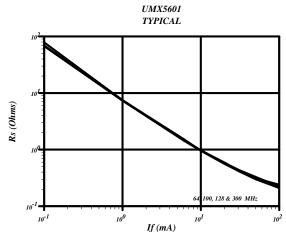
RoHS COMPLIANT











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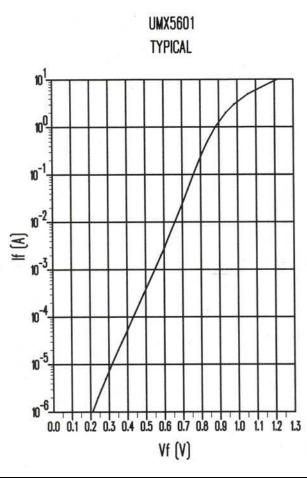
RoHS COMPLIANT

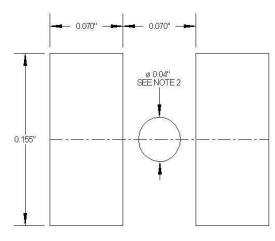




VF VS IF

SM STYLE SOLDER FOOTPRINT



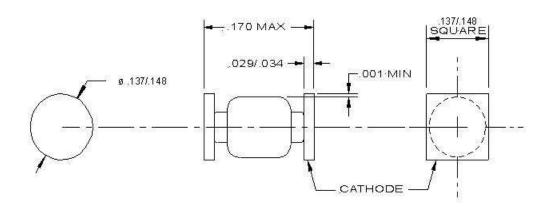


NOTES:

- These dimensions will match the terminals and provide for additional solder fillets at the outboard ends at least as wide as the terminals themselves, assuming accuracy of device placement within .005 inches.
- If the mounting method chosen requires use of an adhesive separate from the solder compound, a round (or square) spot of cement as shown should be centrally located.

Dimensions shown are in inches

"SM" STYLE PACKAGE OUTLINE



DIMENSIONS SHOWN ARE IN INCHES

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